

## Digital transistors (built-in resistors)

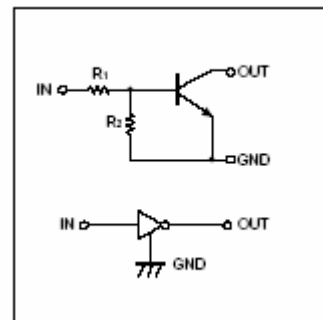
### DTC114EM/DTC114EE/DTC114EUA DTC114EKA /DTC114ECA /DTC114ESA

DIGITAL TRANSISTOR (NPN)

#### FEATURES

1. Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors(see equivalent circuit)
2. The bias resistors consist of thin-film resistors with complete isolation to allow negative biasing of the input.They also have the advantage of almost completely eliminating parasitic effects
3. Only the on/off conditions need to be set for operation, making device design easy

#### ●Equivalent circuit



#### PIN CONNENCTIONS AND MARKING

<p><b>DTC114EE</b></p> <p>1.IN 2.GND 3.OUT</p> <p>SOT-523      Abbreviated symbol: 24</p>	<p><b>DTC114EUA</b></p> <p>1.IN 2.GND 3.OUT</p> <p>SOT-323      Abbreviated symbol: 24</p>
<p><b>DTC114EKA</b></p> <p>1.IN 2.GND 3.OUT</p> <p>SOT-23-3L      Abbreviated symbol: 24</p>	<p><b>DTC114ECA</b></p> <p>1.IN 2.GND 3.OUT</p> <p>SOT-23      Abbreviated symbol: 24</p>
<p><b>DTC114ESA</b></p> <p>1.GND 2.OUT 3.IN</p> <p>TO-92S</p>	<p><b>DTC114EM</b></p> <p>1.IN 2.GND 3.OUT</p> <p>SOT-723      Abbreviated symbol: 24</p>

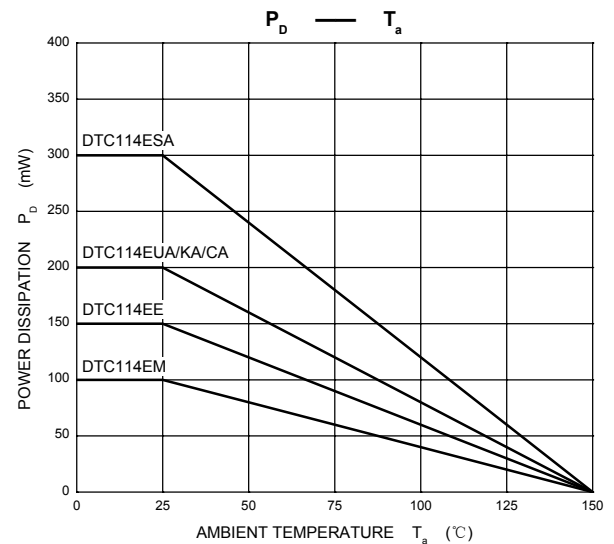
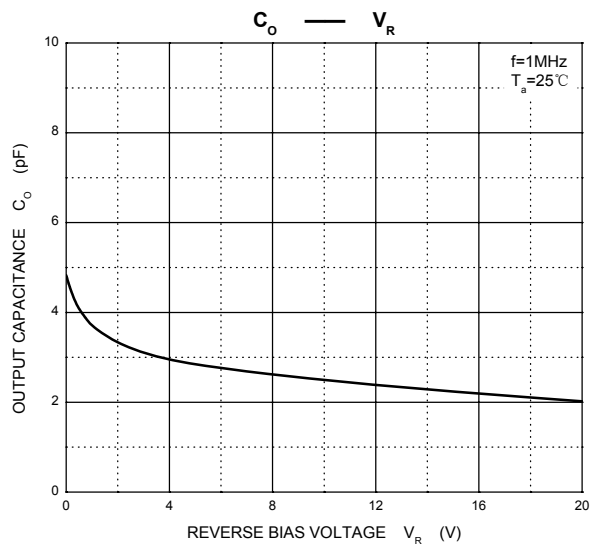
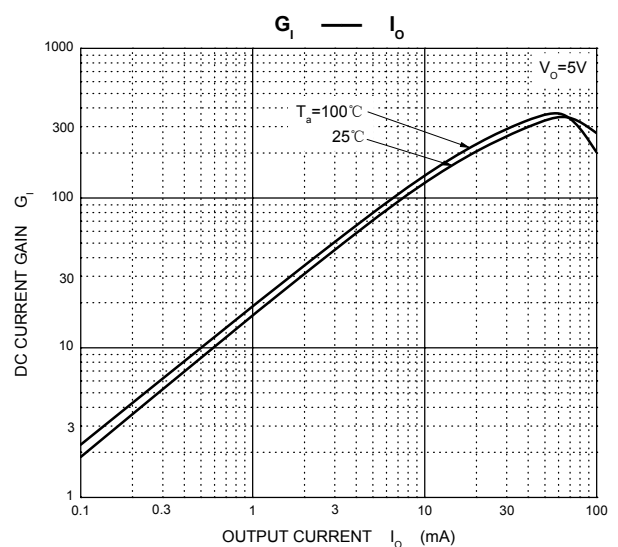
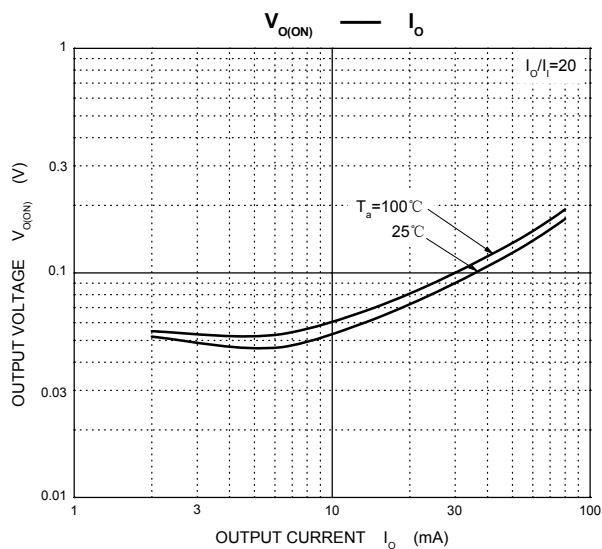
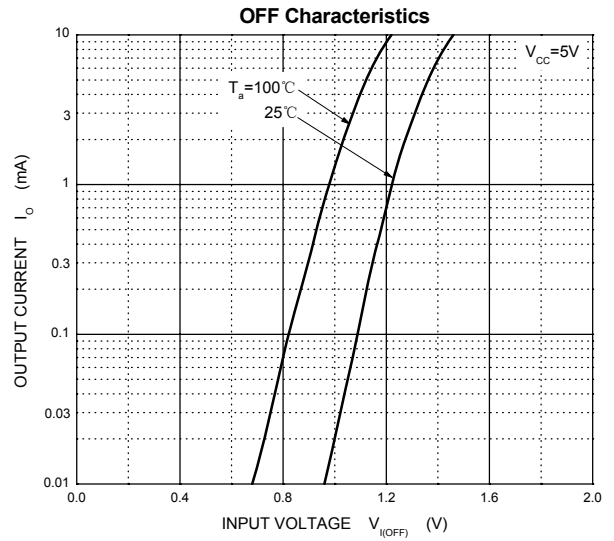
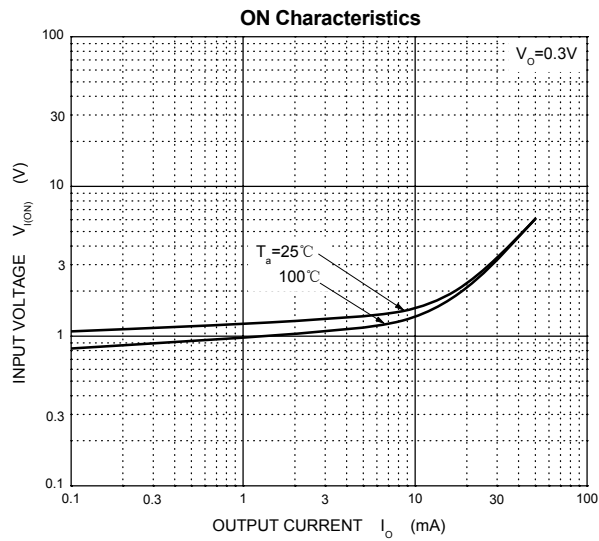
## Absolute maximum ratings(Ta=25°C)

Parameter	Symbol	Limits (DTC114E□)						Unit
		M	E	UA	KA	CA	SA	
Supply voltage	V <sub>CC</sub>	50						V
Input voltage	V <sub>IN</sub>	-10~40						V
Output current	I <sub>O</sub>	50						mA
	I <sub>C(MAX)</sub>	100						
Power dissipation	P <sub>d</sub>	100	150	200		300		mW
Junction temperature	T <sub>j</sub>	150						°C
Storage temperature	T <sub>stg</sub>	-55~150						°C

## Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min	Typ	Max	Unit	Conditions
Input voltage	V <sub>I(off)</sub>	0.5			V	V <sub>CC</sub> =5V, I <sub>O</sub> =100μA
	V <sub>I(on)</sub>			3		V <sub>O</sub> =0.3V, I <sub>O</sub> =10 mA
Output voltage	V <sub>O(on)</sub>			0.3	V	I <sub>O</sub> /I <sub>I</sub> =10mA/0.5mA
Input current	I <sub>I</sub>			0.88	mA	V <sub>I</sub> =5V
Output current	I <sub>O(off)</sub>			0.5	μA	V <sub>CC</sub> =50V, V <sub>I</sub> =0
DC current gain	G <sub>I</sub>	30				V <sub>O</sub> =5V, I <sub>O</sub> =5mA
Input resistance	R <sub>1</sub>	7	10	13	KΩ	
Resistance ratio	R <sub>2</sub> /R <sub>1</sub>	0.8	1	1.2		
Transition frequency	f <sub>T</sub>		250		MHz	V <sub>O</sub> =10V, I <sub>O</sub> =5mA, f=100MHz

## Typical Characteristics



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